MOSFETs Silicon N-channel MOS (U-MOSIV)

TK20S06K3L

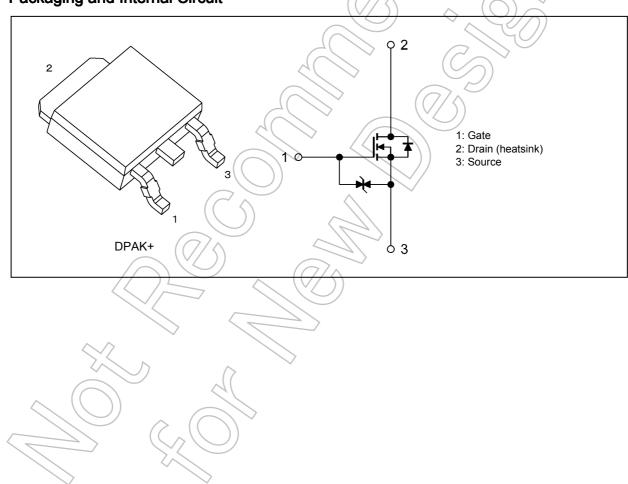
1. Applications

- Automotive
- Motor Drivers
- DC-DC Converters
- Switching Voltage Regulators

2. Features

- (1) AEC-Q101 qualified
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 23 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (3) Low leakage current: $I_{\rm DSS}$ = 10 μA (max) (V_{\rm DS} = 60 V)
- (4) Enhancement mode: $V_{th} = 2.0$ to 3.0 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristi | cs | | Symbol | Rating | Unit |
|-------------------------------|-------------------------|----------|------------------|------------|------|
| Drain-source voltage | | | V _{DSS} | 60 | V |
| Gate-source voltage | | | V _{GSS} | ±20 | |
| Drain current (DC) | | (Note 1) | I _D | 20 | A |
| Drain current (pulsed) | | (Note 1) | I _{DP} | 40 | |
| Power dissipation | (T _c = 25°C) | | PD | 38 | W |
| Single-pulse avalanche energy | | (Note 2) | E _{AS} | 17 | mJ |
| Avalanche current | | | I _{AR} | 20 | A |
| Channel temperature | | (Note 3) | T _{ch} |) 175 | °C |
| Storage temperature | | (Note 3) | T _{stg} | -55 to 175 | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

| (| Characteristics | | Symbol | Max | Unit |
|------------------------------------|--------------------------|------------------------------------|-----------------------|-----|------|
| Channel-to-case thermal resistance | $\angle \langle \rangle$ | $(\vee /)$ | R _{th(ch-c)} | 3.9 | °C/W |
| | | $\overline{\langle \cdot \rangle}$ | / | | |

Note 1: Ensure that the channel temperature does not exceed 175°C.

Note 2: V_{DD} = 25 V, T_{ch} = 25°C (initial), L = 58 μ H, R_G = 1 Ω , I_{AR} = 20 A

Note 3: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

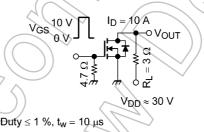
6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|----------------------|---|--------------|--------------------------|-----|------|
| Gate leakage current | I _{GSS} | V_{GS} = ±16 V, V_{DS} = 0 V | _ | _ | ±10 | μA |
| Drain cut-off current | I _{DSS} | V _{DS} = 60 V, V _{GS} = 0 V | Z | _ | 10 | |
| Drain-source breakdown voltage | V _{(BR)DSS} | I _D = 10 mA, V _{GS} = 0 V | 60 | | _ | V |
| | V _{(BR)DSX} | I _D = 10 mA, V _{GS} = -20 V | 40 | $\langle \gamma \rangle$ | _ | |
| Gate threshold voltage | V _{th} | V _{DS} = 10 V, I _D = 1 mA | 2.0 | 2_ | 3.0 | |
| Drain-source on-resistance | R _{DS(ON)} | V _{GS} = 6 V, I _D = 10 A | $/ \uparrow$ | 26 | 40 | mΩ |
| | | V _{GS} = 10 V, I _D = 10 A | \sum | 23 | 29 | |

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|------------------|--|--------|------|-----|------|
| Input capacitance | C _{iss} | V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz | - / | 780 | Ι | pF |
| Reverse transfer capacitance | C _{rss} | | ((| 75 | | |
| Output capacitance | C _{oss} | | | 136 |) — | |
| Switching time (rise time) | tr | See Figure 6.2.1. | \sim | 8 | — | ns |
| Switching time (turn-on time) | t _{on} | | | 16 | — | |
| Switching time (fall time) | t _f | | | 6 | _ | |
| Switching time (turn-off time) | t _{off} | | | 24 | _ | |





6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|---|-----------------|--|-----|------|-----|------|
| Total gate charge (gate-source plus gate-drain) | Qg | $V_{DD} \approx 48 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 20 \text{ A}$ | — | 18 | _ | nC |
| Gate-source charge | Q _{gs} | | _ | 12 | _ | |
| Gate-drain charge | Q _{gd} | | _ | 6 | _ | |

6.4. Source-Drain Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

| Characteristics | \square | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------|-----------|------------------|---|-----|------|------|------|
| Reverse drain current (DC) | (Note 4) | I _{DR} | — | _ | _ | 20 | А |
| Reverse drain current (pulsed) | (Note 4) | I _{DRP} | — | _ | _ | 40 | |
| Diode forward voltage | | V _{DSF} | I _{DR} = 20 A, V _{GS} = 0 V | _ | _ | -1.2 | V |
| Reverse recovery time | | t _{rr} | I _{DR} = 20 A, V _{GS} = 0 V | | 36 | | ns |
| Reverse recovery charge | | Q _{rr} | -dI _{DR} /dt = 50 A/μs | _ | 22 | _ | nC |

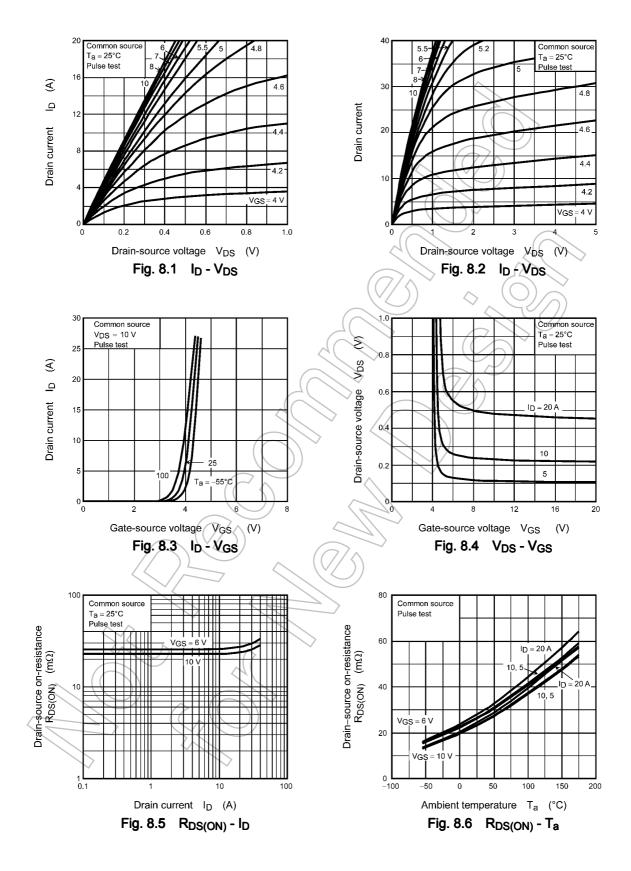
Note 4: Ensure that the channel temperature does not exceed 175°C.

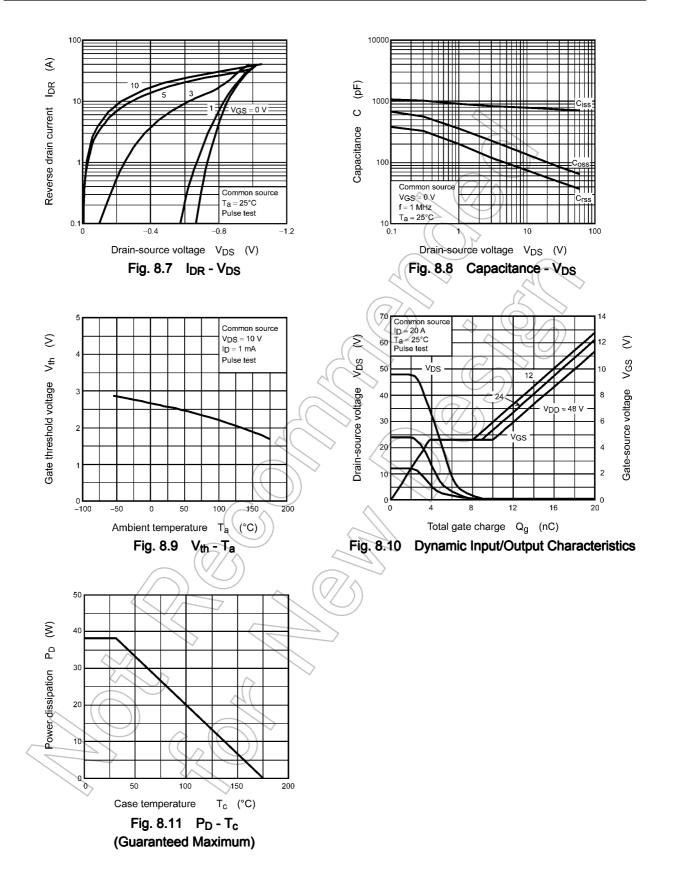
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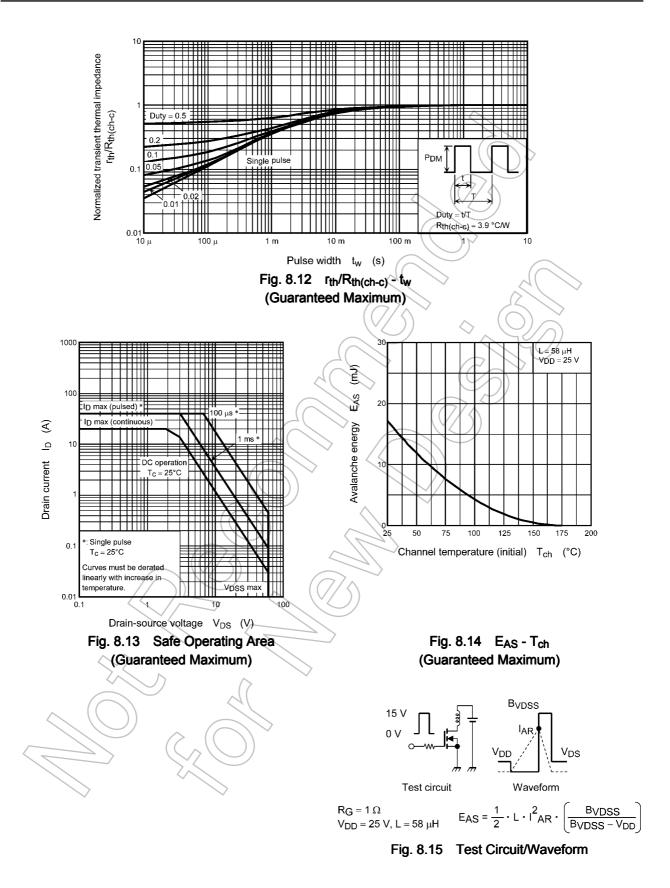
TOSHIBA 7. Marking (Note)

| | K20S06K3 ← Part No. (or abbreviation code) L Lot No. Note |
|-------|--|
| | Fig. 7.1 Marking |
| Note: | A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment. |
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8. Characteristics Curves (Note)







Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

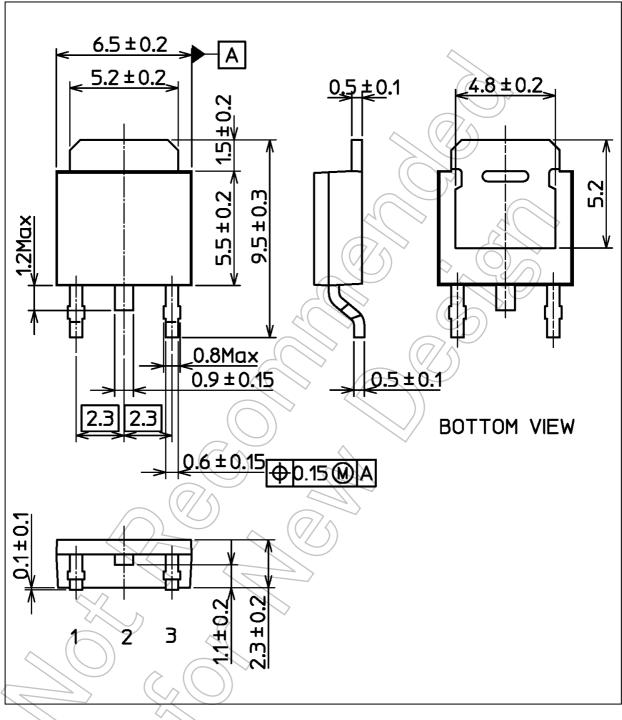
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Package Dimensions

TK20S06K3L

Unit: mm



Weight: 0.36 g (typ.)

| | Package Name(s) | |
|-----------------|-----------------|--|
| TOSHIBA: 2-7M1A | | |
| Nickname: DPAK+ | | |

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